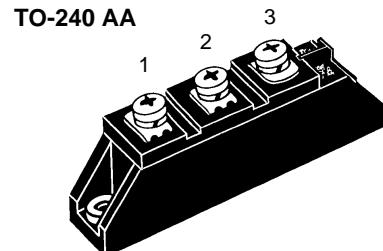
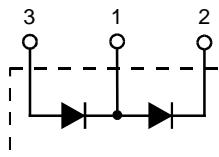


Diode Modules

I_{FRMS} = 2x 180 A
I_{FAVM} = 2x 120 A
V_{RRM} = 800-2200 V

V _{RSM} V	V _{RRM} V	Type
900	800	MDD 95-08N1 B
1300	1200	MDD 95-12N1 B
1500	1400	MDD 95-14N1 B
1700	1600	MDD 95-16N1 B
1900	1800	MDD 95-18N1 B
2100	2000	MDD 95-20N1 B
2300	2200	MDD 95-22N1 B



Symbol	Test Conditions	Maximum Ratings	
I _{FRMS}	T _{VJ} = T _{VJM}	180	A
I _{FAVM}	T _C = 105°C; 180° sine	120	A
I _{FSM}	T _{VJ} = 45°C; V _R = 0	2800	A
	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	3300	A
	T _{VJ} = T _{VJM} V _R = 0	2500	A
	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	2750	A
j ² dt	T _{VJ} = 45°C V _R = 0	39 200	A ² s
	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	45 000	A ² s
	T _{VJ} = T _{VJM} V _R = 0	31 200	A ² s
	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	31 300	A ² s
T _{VJ}		-40...+150	°C
T _{VJM}		150	°C
T _{stg}		-40...+125	°C
V _{ISOL}	50/60 Hz, RMS	t = 1 min	3000 V~
	I _{ISOL} ≤ 1 mA	t = 1 s	3600 V~
M _d	Mounting torque (M5)	2.5-4/22-35	Nm/lb.in.
	Terminal connection torque (M5)	2.5-4/22-35	Nm/lb.in.
Weight	Typical including screws	90	g

Symbol	Test Conditions	Characteristic Values	
I _R	T _{VJ} = T _{VJM} ; V _R = V _{RRM}	15	mA
V _F	I _F = 300 A; T _{VJ} = 25°C	1.43	V
V _{T0}	For power-loss calculations only	0.75	V
r _T	T _{VJ} = T _{VJM}	1.95	mΩ
Q _S	T _{VJ} = 125°C; I _F = 50 A, -di/dt = 6 A/μs	170	μC
I _{RM}		45	A
R _{thJC}	per diode; DC current	0.26	K/W
	per module	0.13	K/W
R _{thJK}	per diode; DC current	0.46	K/W
	per module	0.23	K/W
d _s	Creepage distance on surface	12.7	mm
d _A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
 IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al₂O₃-ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

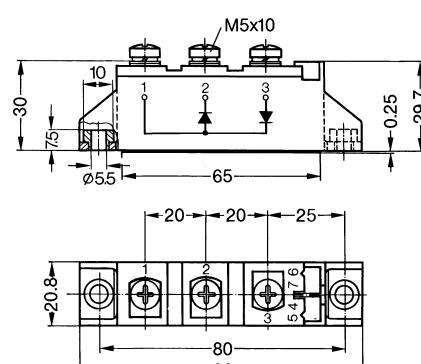
Applications

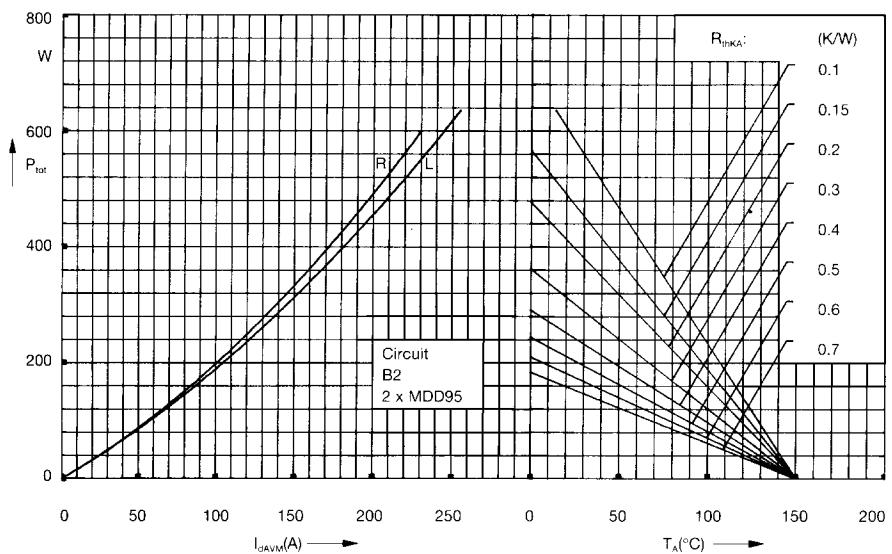
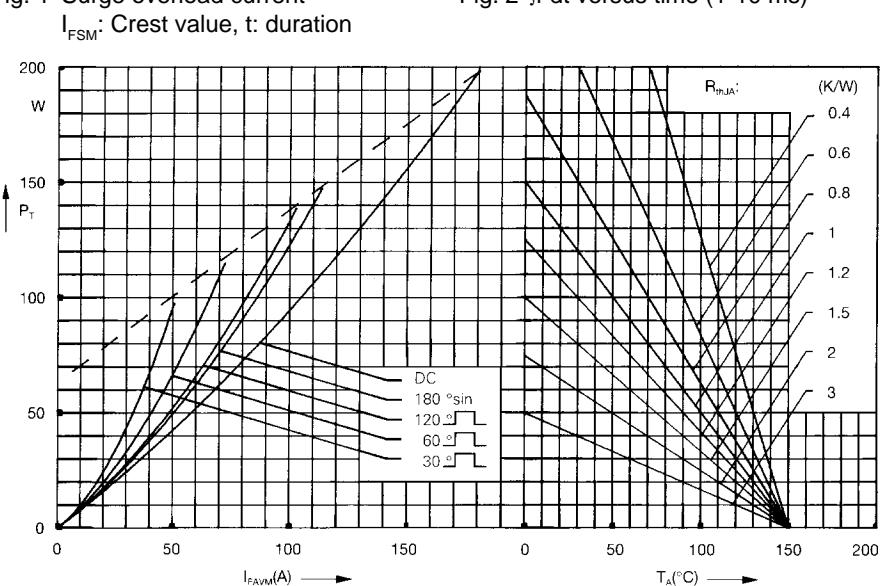
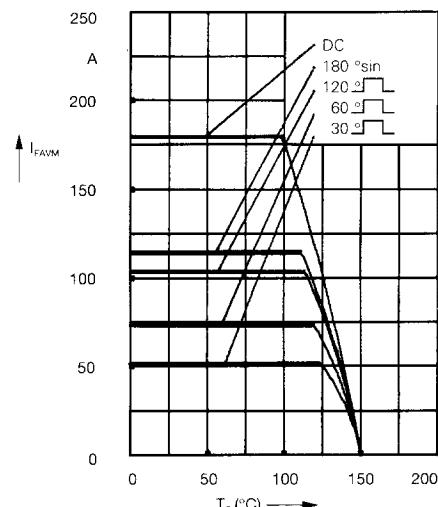
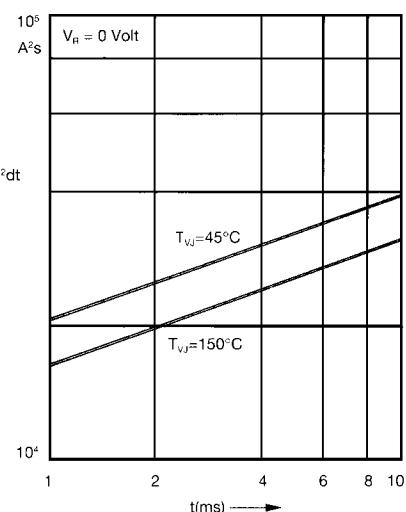
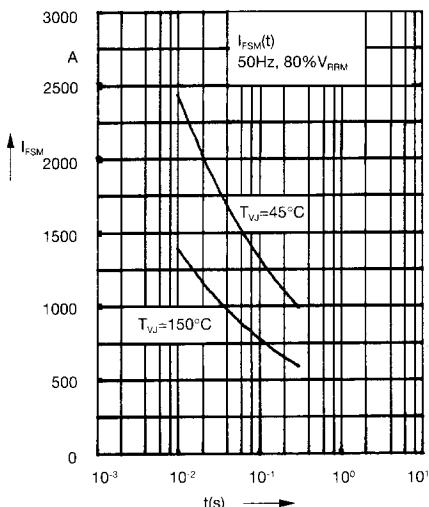
- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")





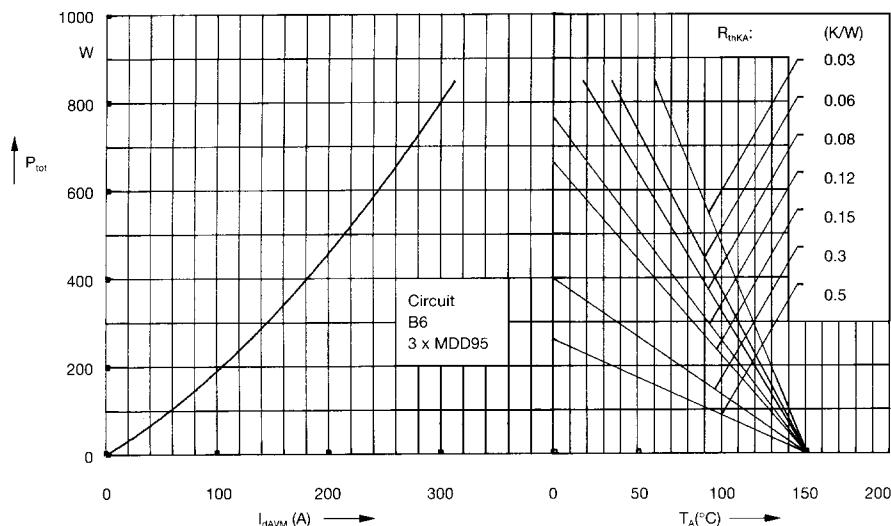


Fig. 5 Three phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature

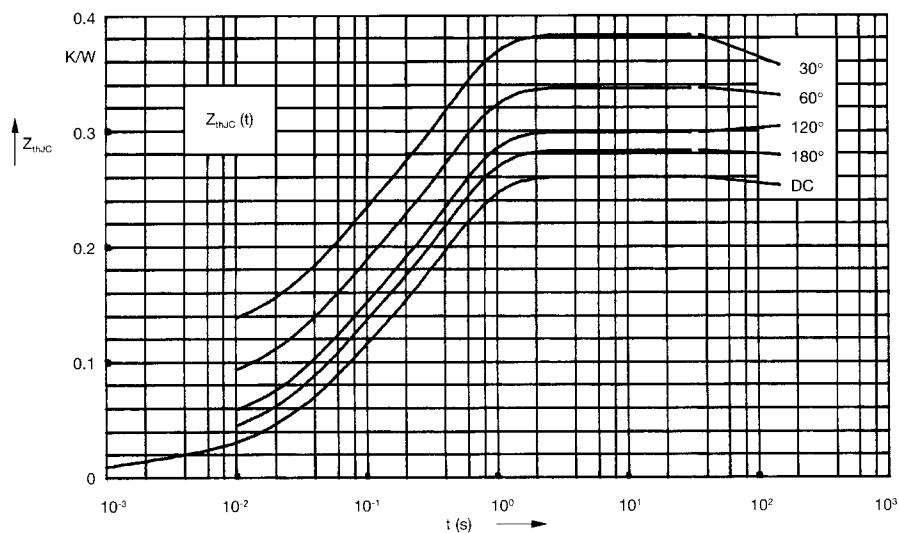


Fig. 6 Transient thermal impedance
junction to case (per diode)

d	R_{thJC} (K/W)
DC	0.26
180°	0.28
120°	0.30
60°	0.34
30°	0.38

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.013	0.0012
2	0.072	0.047
3	0.175	0.394

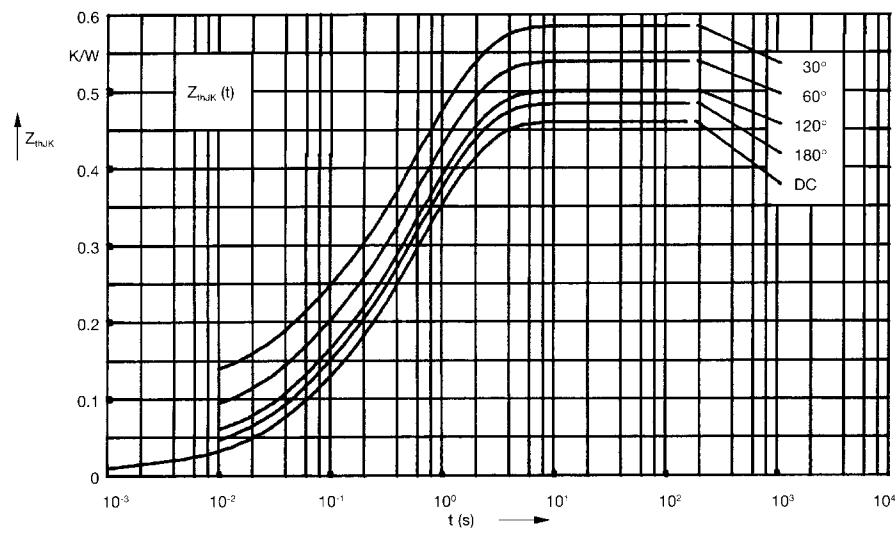


Fig. 7 Transient thermal impedance
junction to heatsink (per diode)

d	R_{thJK} (K/W)
DC	0.46
180°	0.48
120°	0.50
60°	0.54
30°	0.58

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.013	0.0012
2	0.072	0.047
3	0.175	0.394
4	0.2	1.32